

**SEMITOP® 3**

## Antiparallel Thyristor Module

### SK 25 UT

Preliminary Data

#### Features

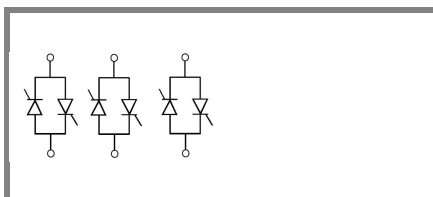
- Compact Design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

#### Typical Applications\*

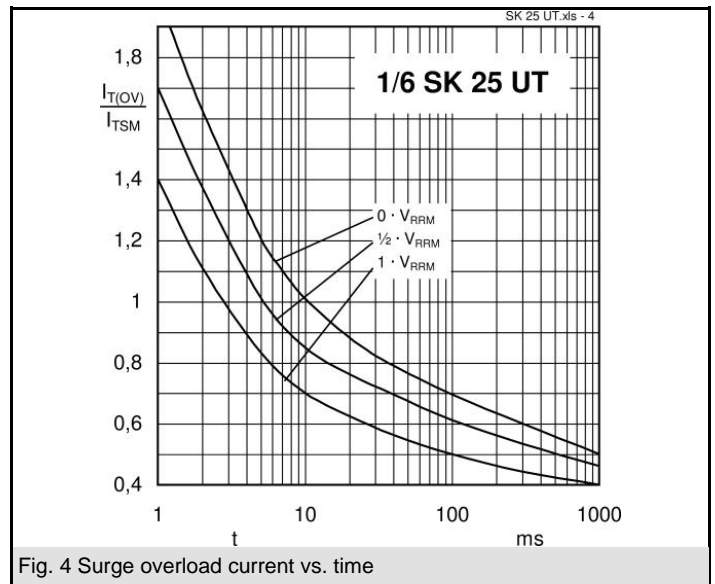
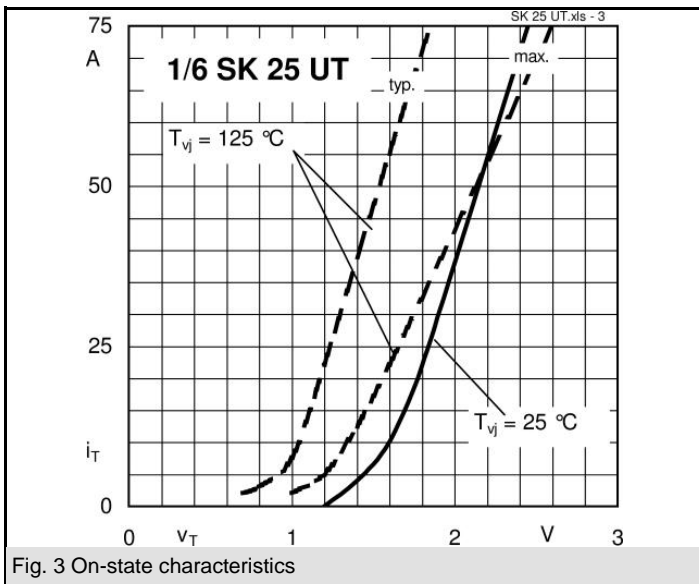
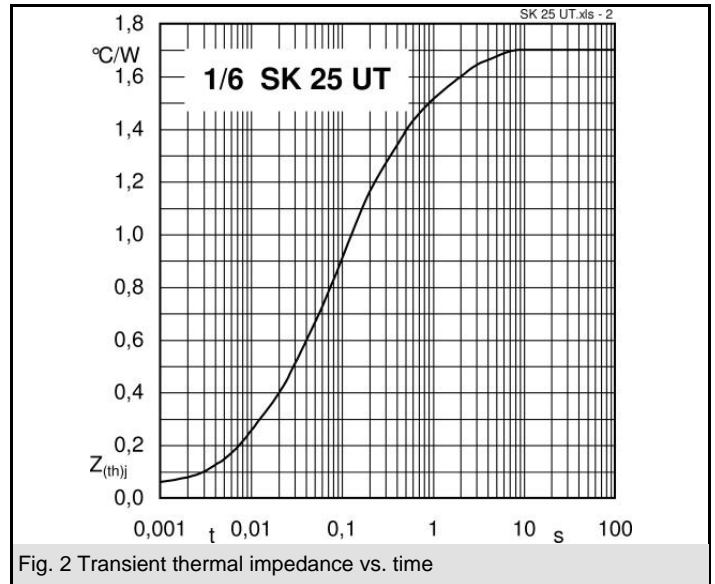
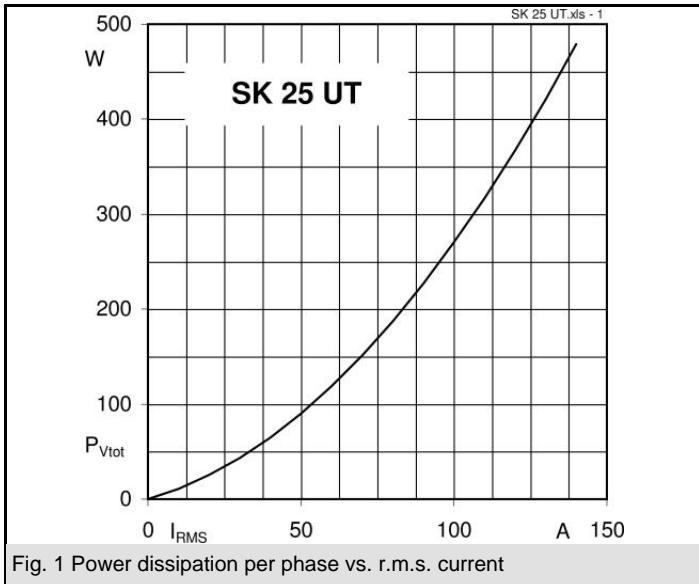
- Soft starters
- Light control (studios, theaters...)
- Temperature control

$V_{RSM}$ V	$V_{RRM}, V_{DRM}$ V	$I_{RMS} = 29$ A (full conduction) ( $T_s = 85^\circ\text{C}$ )
900	800	SK 25 UT 08
1300	1200	SK 25 UT 12
1700	1600	SK 25 UT 16

Symbol	Conditions	Values	Units
$I_{RMS}$	W1C ; sin. $180^\circ$ ; $T_s = 100^\circ\text{C}$	20	A
	W1C ; sin. $180^\circ$ ; $T_s = 85^\circ\text{C}$	29	A
$I_{TSM}$	$T_{vj} = 25^\circ\text{C}$ ; 10 ms	320	A
	$T_{vj} = 125^\circ\text{C}$ ; 10 ms	280	A
$i^2t$	$T_{vj} = 25^\circ\text{C}$ ; 8,3...10 ms	510	A <sup>2</sup> s
	$T_{vj} = 125^\circ\text{C}$ ; 8,3...10 ms	390	A <sup>2</sup> s
$V_T$	$T_{vj} = 25^\circ\text{C}$ , $I_T = 75$ A	max. 2,45	V
$V_{T(TO)}$	$T_{vj} = 125^\circ\text{C}$	max. 1,1	V
$r_T$	$T_{vj} = 125^\circ\text{C}$	max. 20	m $\Omega$
$I_{DD}, I_{RD}$	$T_{vj} = 125^\circ\text{C}$ , $V_{RD} = V_{RRM}$	max. 8	mA
$t_{gd}$	$T_{vj} = 25^\circ\text{C}$ , $I_G = 1$ A; $di_G/dt = 1$ A/ $\mu\text{s}$	1	$\mu\text{s}$
$t_{gr}$	$V_D = 0,67 * V_{DRM}$	1	$\mu\text{s}$
$(dv/dt)_{cr}$	$T_{vj} = 125^\circ\text{C}$	1000	V/ $\mu\text{s}$
$(di/dt)_{cr}$	$T_{vj} = 125^\circ\text{C}$ ; $f = 50...60$ Hz	50	A/ $\mu\text{s}$
$t_q$	$T_{vj} = 125^\circ\text{C}$ ; typ.	80	$\mu\text{s}$
$I_H$	$T_{vj} = 25^\circ\text{C}$ ; typ. / max.	80 / 150	mA
$I_L$	$T_{vj} = 25^\circ\text{C}$ ; $R_G = 33 \Omega$ ; typ. / max.	150 / 300	mA
$V_{GT}$	$T_{vj} = 25^\circ\text{C}$ ; d.c.	min. 2	V
$I_{GT}$	$T_{vj} = 25^\circ\text{C}$ ; d.c.	min. 100	mA
$V_{GD}$	$T_{vj} = 125^\circ\text{C}$ ; d.c.	max. 0,25	V
$I_{GD}$	$T_{vj} = 125^\circ\text{C}$ ; d.c.	max. 3	mA
$R_{th(j-s)}$	cont. per thyristor	1,7	K/W
	sin $180^\circ$ per thyristor	1,78	K/W
$R_{th(j-s)}$	cont. per W1C	0,85	K/W
	sin $180^\circ$ per W1C	0,89	K/W
$T_{vj}$		-40 ... +125	$^\circ\text{C}$
$T_{stg}$		-40 ... +125	$^\circ\text{C}$
$T_{solder}$	terminals, 10s	260	$^\circ\text{C}$
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 / 2500	V~
$M_s$	Mounting torque to heatsink	2,5	Nm
$M_t$			Nm
$a$			m/s <sup>2</sup>
$m$		30	g
Case	SEMITOP® 3	T 13	



UT



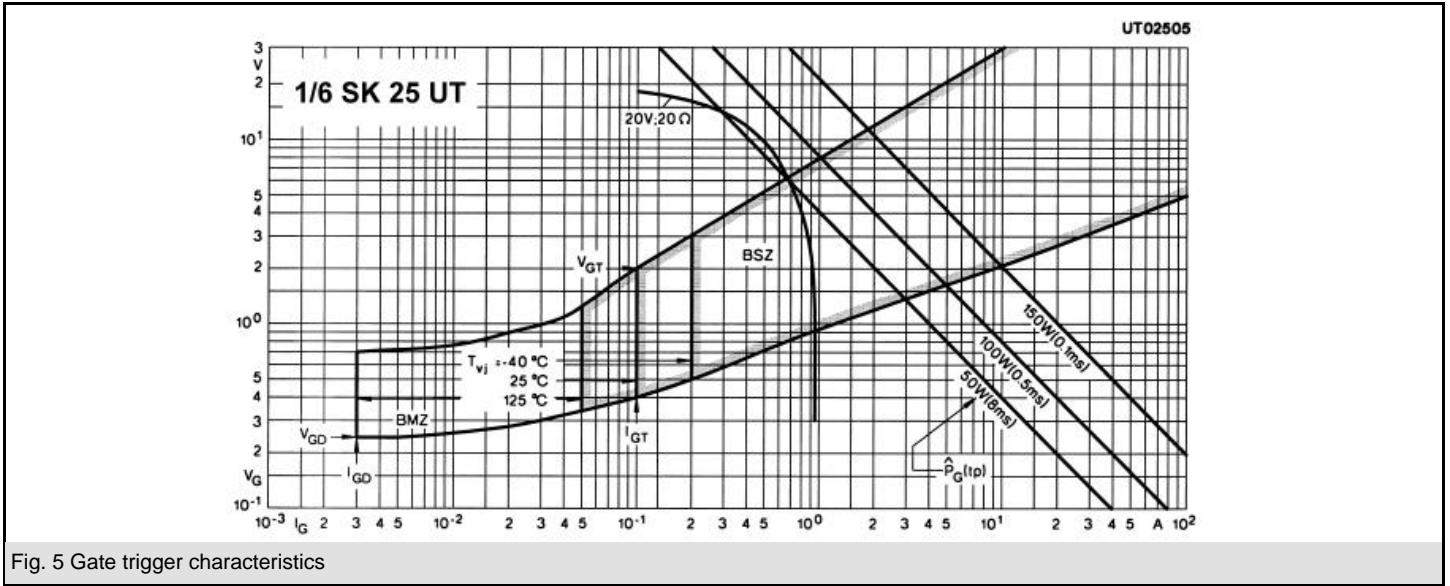
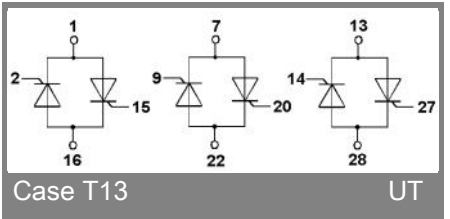
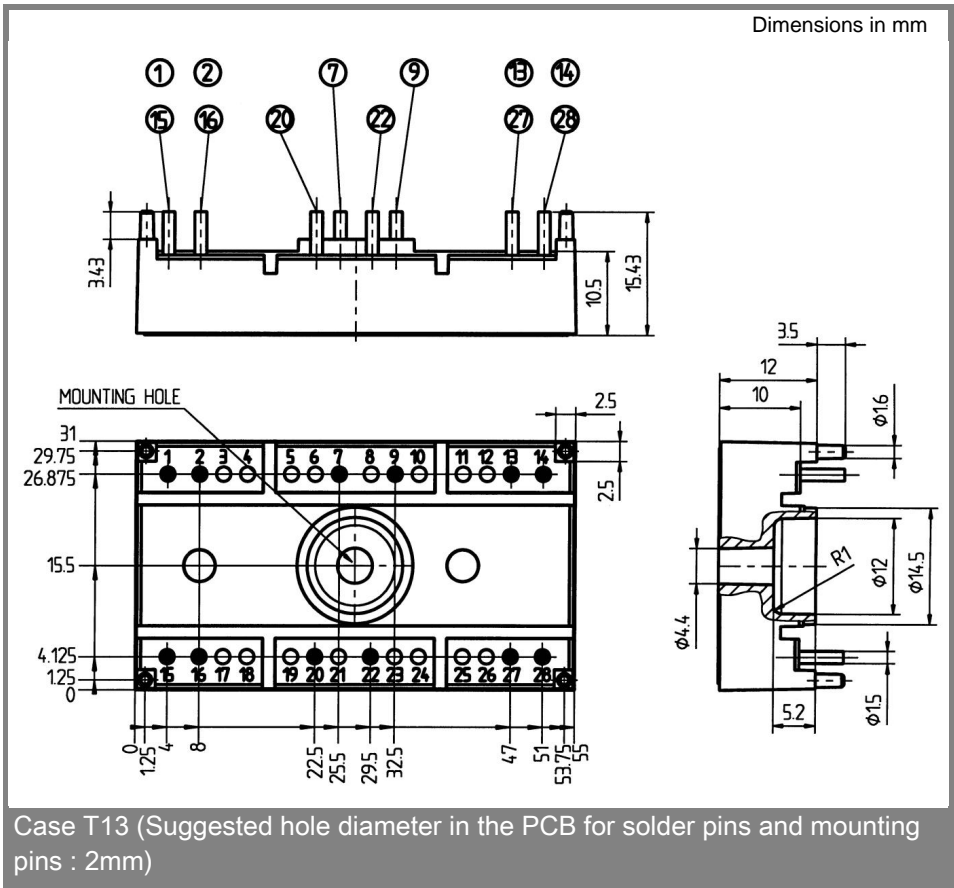


Fig. 5 Gate trigger characteristics



\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.